Unit: mm

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (L^2 - π -MOSV)

2SK2267

Chopper Regulator, DC-DC Converter and Motor Drive Applications

4-V gate drive

• Low drain-source ON-resistance : $R_{DS(ON)} = 8 \text{ m}\Omega \text{ (typ.)}$

• High forward transfer admittance : $|Y_{fs}| = 60 \text{ S (typ.)}$

Low leakage current : I_{DSS} = 100 μA (max) (V_{DS} = 60 V)

• Enhancement mode : $V_{th} = 0.8$ to 2.0 V ($V_{DS} = 10$ V, $I_D = 1$ mA)

Absolute Maximum Ratings (Ta = 25°C)

| Characteri | stics | Symbol | Rating | Unit |
|---------------------------|------------------------|------------------|------------|------|
| Drain-source voltage | | V_{DSS} | 60 | V |
| Drain-gate voltage (R | _{GS} = 20 kΩ) | V_{DGR} | 60 | V |
| Gate-source voltage | | V _{GSS} | ±20 | V |
| Drain current | DC (Note 1) | I _D | 60 | Α |
| | Pulse (Note 1) | I_{DP} | 240 | Α |
| Drain power dissipatio | n (Tc = 25°C) | P_{D} | 150 | W |
| Single pulse avalanche | e energy (Note 2) | E _{AS} | 1054 | mJ |
| Avalanche current | | I _{AR} | 60 | Α |
| Repetitive avalanche | energy (Note 3) | E _{AR} | 15 | mJ |
| Channel temperature | | T _{ch} | 150 | °C |
| Storage temperature range | | T _{stg} | -55 to 150 | °C |

20.5 max #3.3±0.2

20.5 max #3.3±0.2

0.5 max #3.5±0.15

0.5 max #3.

2-21F1B

Weight: 9.75 g (typ.)

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Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

| Characteristics | Symbol | Max | Unit |
|--|------------------------|-------|------|
| Thermal resistance, channel to case | R _{th (ch-c)} | 0.833 | °C/W |
| Thermal resistance, channel to ambient | R _{th (ch-a)} | 35.7 | °C/W |

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V_{DD} = 25 V, T_{ch} = 25°C (initial), L = 398 μ H, R_{G} = 25 Ω , I_{AR} = 60 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device.

Please handle with caution.



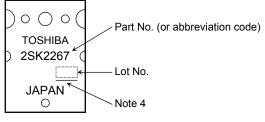
Electrical Characteristics (Ta = 25°C)

| Charac | cteristics | Symbol | Test Condition | Min | Тур. | Max | Unit | |
|---|-----------------|----------------------|--|-----|------|-----|------|--|
| Gate leakage cu | ırrent | I _{GSS} | V _{GS} = ±16 V, V _{DS} = 0 V | _ | _ | ±10 | μΑ | |
| Drain cut-off cu | rrent | I _{DSS} | V _{DS} = 60 V, V _{GS} = 0 V | _ | _ | 100 | μΑ | |
| Drain-source br | eakdown voltage | V (BR) DSS | I _D = 10 mA, V _{GS} = 0 V | 60 | _ | _ | V | |
| Gate threshold v | /oltage | V _{th} | V _{DS} = 10 V, I _D = 1 mA | 0.8 | _ | 2.0 | V | |
| Drain-source ON-resistance | | R _{DS (ON)} | V _{GS} = 4 V, I _D = 30 A | _ | 12 | 15 | - mΩ | |
| | | | V _{GS} = 10 V, I _D = 30 A | _ | 8 | 11 | | |
| Forward transfer | r admittance | Y _{fs} | V _{DS} = 10 V, I _D = 30 A | 40 | 60 | _ | S | |
| Input capacitano | e | C _{iss} | | | 5500 | _ | pF | |
| Reverse transfer capacitance | | C _{rss} | C _{rss} V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz | _ | 920 | _ | | |
| Output capacitance | | C _{oss} | | | 2600 | _ | | |
| Switching time | Rise time | t _r | V _{GS} _{0V} I _D =30A OV _{OUT} R _L =1Ω | _ | 30 | _ | | |
| | Turn-on time | t _{on} | | _ | 60 | _ |] | |
| | Fall time | t _f | | _ | 65 | _ | ns | |
| | Turn-off time | t _{off} | $V_{DD} = 30V$ Duty $\leq 1\%$, $t_{W} = 10 \mu s$ | _ | 220 | _ | | |
| Total gate charge (Gate–source plus gate–drain) | | Qg | | _ | 170 | 1 | | |
| Gate-source charge | | Q _{gs} | $V_{DD} \approx 48 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 60 \text{ A}$ | | 110 | | nC | |
| Gate-drain ("miller") charge | | Q _{gd} | | _ | 60 | _ | | |

Source-Drain Ratings and Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|------------------|---|-----|------|------|------|
| Continuous drain reverse current (Note 1) | I _{DR} | _ | _ | _ | 60 | Α |
| Pulse drain reverse current (Note 1) | I _{DRP} | _ | _ | _ | 240 | Α |
| Forward voltage (diode) | V _{DSF} | I _{DR} = 60 A, V _{GS} = 0 V | _ | _ | -1.7 | V |
| Reverse recovery time | t _{rr} | I _{DR} = 60 A, V _{GS} = 0 V | | 150 | _ | ns |
| Reverse recovered charge | Q_{rr} | dl _{DR} / dt = 50 A / μs | | 0.3 | _ | μC |

Marking

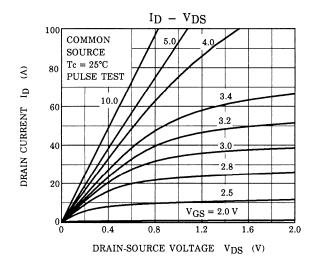


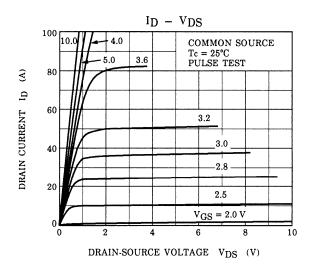
Note 4: A line under a Lot No. identifies the indication of product Labels.

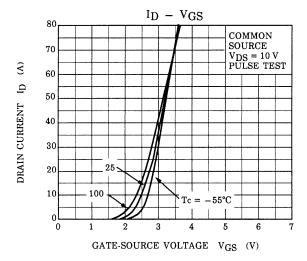
Not underlined: [[Pb]]/INCLUDES > MCV

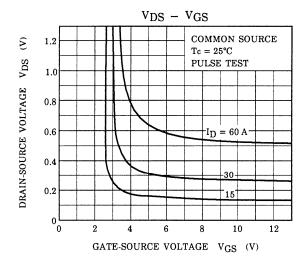
Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

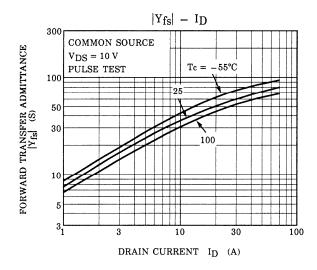
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

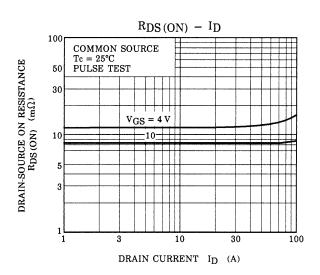




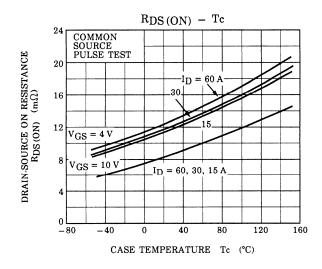


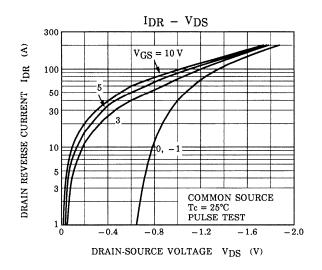


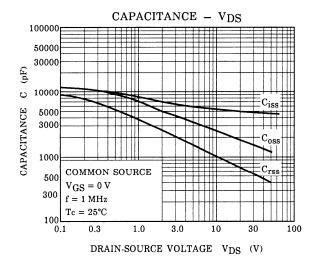


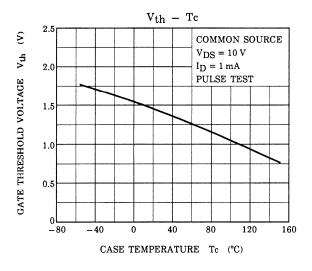


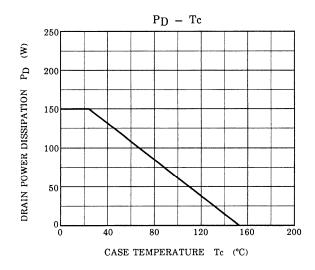
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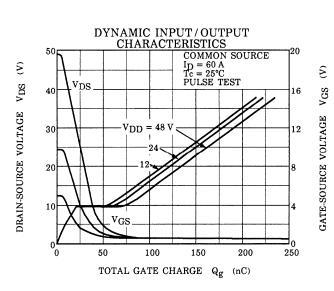




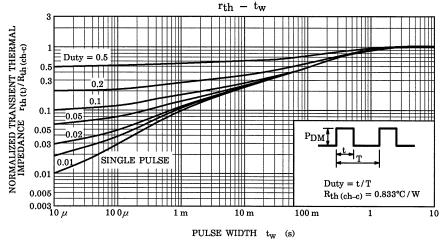




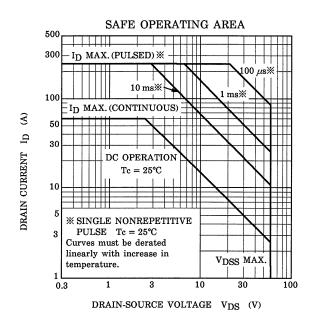


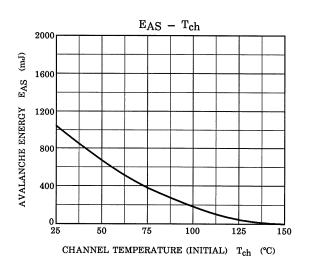


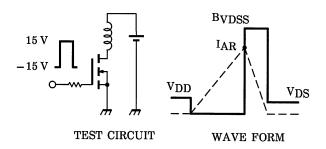
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$$\begin{aligned} R_G &= 25~\Omega \\ V_{DD} &= 25~V,~L = 398~\mu H \end{aligned} \qquad EAS &= \frac{1}{2} \cdot L \cdot I^2 \cdot \left(\frac{BVDSS}{BVDSS - VDD} \right) \end{aligned}$$

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